Route to Ferromagnetism in Organic Polymers

Zsolt Gulácsi,1,2 Arno Kampf,1 and Dieter Vollhardt1

1Theoretical Physics III, Center for Electronic Correlations and Magnetism, Institute of Physics, University of Augsburg, D-86135 Augsburg, Germany
2Department of Theoretical Physics, University of Debrecen, H-4010 Debrecen, Hungary

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Employing a rigorous theoretical method for the construction of exact many-electron ground states we prove that interactions can be employed to tune a bare dispersive band structure such that it develops a flat band. Thereby, we show that pentagon-chain polymers with electron densities above half filling may be designed to become ferromagnetic or half metallic.

Conducting polymers [1] are a fascinating class of materials with a strikingly wide range of applications, e.g., in nanoelectronics [2], nanooptics [3], and medicine [4]. Many of them contain chains of five-membered rings as a building block. Such pentagon-chain polymers have been explored [5,6] and utilized [2] intensively in the past. In particular, polythiophene [7–9] was studied in the search for plastic ferromagnets and, more generally, for ferromagnetism in systems made entirely of nonmagnetic elements. The possibility for ferromagnetism in these systems was investigated theoretically [10,11], with a particular focus on ferromagnetism due to flat electronic bands arising in odd-membered ring structures [12]. Particular attention was paid to the role of side groups of the pentagon ring, since these may cause flat bands in the band structure. Suwa et al. [13] proposed that ferromagnetism in pentagon-chain polymers such as polydimethylaminopyrrole is related to the hybridization of narrow \( \sigma \) bands with wide \( \pi \) bands and therefore modeled this polymer by a periodic Anderson model. In the latter model the electronic interaction acts site selective within the unit cell and the choice of this model [13] was an attempt to account for the different atoms on the pentagon chain.

In this Letter we investigate pentagon-chain polymers (see Fig. 1) by a general multiband Hubbard model where the electrons experience local Coulomb interactions on all lattice sites. The microscopic parameters are chosen such that they account for the particular environment and type of atom in the unit cell of the material; in particular, in our approach repulsive on-site interactions are permitted to differ on individual sites. Similarly, we also include bond dependent hopping amplitudes. The hopping parameters are not assumed to take special values leading to flat bands in the bare band structure. By contrast we will show rigorously that the dispersion of the correlated system may be tuned by the interaction to become flat. Thereby transitions to ferromagnetic states or correlated half-metallic states at high electron densities may be induced. We thus prove by exact means the conjecture of Brocks et al. [14] that the Coulomb interaction is able to stabilize magnetic order in acene and thiophene.

Our analytic approach proceeds in three steps: the transformation of the Hamiltonian into positive semidefinite form, the construction of ground states, and the proof of their uniqueness. This technique is independent of the spatial dimension and does not require integrability of the model. Previously it was successfully applied to construct exact ground states for Hubbard chains with other geometrical structures [15] and even for the three-dimensional periodic Anderson model [16]. Details of the method are described in Ref. [15].

Since the analytic technique employed here is applicable to a large class of chains we discuss it in its general form, and then specify it to a model analysis of the organic pentagon chain shown in Fig. 1. The unit cell contains \( m = m_p + m_r \geq 2 \) sites where \( m_p \) is the number of sites in the closed polygon as indicated in Fig. 2. In this case \( m_p = 5 \), and \( m_r = 1 \) is the number of sites in the side groups; the number \( m \) (here \( m = 6 \)) also determines the number of sublattices. The \( i \)th unit cell then contains the sites \( i + r_i \), \( n \leq m \), with \( r_1 = 0 \) and \( r_{m+1} = a \); here \( |a| \) is the lattice constant. Altogether the chain consists of \( N_c \) cells, where neighboring cells connect through the single point \( r_{m+1} \). Subsequently, we use periodic boundary conditions and fix the number of electrons to \( N \leq N_A \), where \( N_A = mN_c \) is

![FIG. 1 (color online). Schematic view of the pentagon-chain polymer polyaminotriazole. The dotted square indicates the cell presented in detail in Fig. 2.](image-url)
 Altogether, linear superpositions of creation operators acting on blocks and on-site Coulomb interactions, respectively, defined at momentum representation) mean sums and products, inside the cell. The case of a primitive translation vector, and \( m = 1 \) the number of sites. The filling is denoted by \( \rho = N/N_\Lambda \leq 1 \). In the following \( \sum_i, \Pi_i \) (or \( \sum_k, \Pi_k \) in momentum representation) mean sums and products, respectively, over the \( N_c \) cells.

The Hamiltonian we choose to describe the polymer chain has the form \( \hat{H} = \hat{H}_0 + \hat{H}_U \) with

\[
\hat{H}_0 = \sum_{\sigma, \alpha} \sum_{n, n'} \left( t_{n,n'} \hat{c}_{i,n}^\dagger \hat{c}_{i+n',\alpha} + \text{H.c.} \right) + \sum_{\sigma, \alpha} \sum_{n=1} \epsilon_n \hat{n}_{i,n,\sigma},
\]

\[
\hat{H}_U = \sum_i \sum_n U_n \hat{n}_{i+n,\sigma} \hat{n}_{i,n,\sigma}.
\]

Here, \( \hat{c}^\dagger_{i,\sigma} \) creates an electron with spin \( \sigma \) at site \( i \), \( t_{n,n'} \) are hopping matrix elements connecting the sites \( i + r_n \) and \( i + r_{n'} \). Furthermore, \( \epsilon_n \) and \( U_n > 0 \) are on-site potentials and on-site Coulomb interactions, respectively, defined at the sites \( i + r_n \). The Fourier transform of \( \hat{c}_{i+n,\sigma} \) will be denoted by \( \hat{c}_{n,\alpha,\sigma} \). We note that the Hamiltonian parameters are arbitrary at this point, i.e., they are not chosen to provide flat bands in the bare band structure. The case \( \epsilon_n = 0 \) for all \( n \) leaves the results qualitatively unchanged.

In the first step, we define \( m - 1 \) block operators \( \hat{G}^\dagger_{\alpha,\sigma} = \sum_{\epsilon \in B_{\alpha,\sigma}} \sum_{\alpha,\epsilon} \hat{c}_{i,\epsilon}^\dagger \hat{c}_{i+r_n,\sigma} \) with \( \alpha = 1, \ldots, m - 1 \), i.e., linear superpositions of creation operators acting on blocks \( B_{\alpha,\sigma} \) consisting of the \( m \) sites \( i + r_n \) in the unit cell at \( i \); here \( a_{\alpha,\epsilon} \) are numerical coefficients. Specifically for the pentagon cell shown in Fig. 2 we employ 3 three-site blocks [the triangles made of sites (1,2,5), (2,3,5), (3,4,5)], and 2 two-site blocks [the site pairs (5,6), (4,7)] [17].

The interaction term \( \hat{H}_U \) is rewritten in terms of the operators \( \hat{P}_n = \sum_i \hat{P}_{i+n,\sigma} \), where \( \hat{P}_j = \hat{n}_{j+1,\sigma} \hat{n}_{j+1} - (\hat{n}_{j+1} + \hat{n}_{j+1}) + 1 \) is a positive semidefinite operator with eigenvalue zero when there is at least one electron on site \( j \). Altogether, \( \hat{H} - C_g \) takes the positive semidefinite form \( \hat{H} - C_g = \hat{H}_0 + \hat{H}_p \), where

\[
\hat{H}_G = \sum_{n=1}^{m-1} \sum_{\sigma, \alpha} \hat{G}_{\alpha,\sigma}^\dagger \hat{G}_{\alpha,\sigma}, \quad \hat{H}_P = \sum_{n=1}^{m-1} U_n \hat{P}_n.
\]

Here, \( C_g = q_U N - N_c \sum_{n=1}^{m-1} U_n + 2 \sum_{n=1}^{m-1} z_a \), \( z_a = \sum |a_{\alpha,\epsilon}|^2 \), and \( q_U \) are constants which depend on the parameters entering in \( \hat{H} \). The transformation of \( \hat{H} \) into the semidefinite form shown in Eq. (2) requires that the microscopic parameters in Eq. (1) fulfill certain conditions, i.e., equations connecting the coefficients \( a_{\alpha,\epsilon} \) and \( q_U \) to the starting Hamiltonian parameters in Eq. (1). The solvability of the matching conditions determines the parameter space domain \( \mathcal{D} \) for which the transformation from Eq. (1) to Eq. (2) can be performed. It is not difficult to show that \( \mathcal{D} \) is not strongly restricted by the Hamiltonian parameters in Eq. (1). In particular, the values of the interaction parameters \( U_n \) can vary over a wide range.

Details regarding the form of the matching conditions, the domain \( \mathcal{D} \), and the block operators \( \hat{G}_{\alpha,\sigma} \) in Eq. (2) are presented in [18].

Before we construct ground states of Eq. (2) above half filling \( \rho > 1/2 \) we analyze its effective band structure. This is possible because the anticommutation relations for the composite block operators \( \hat{G}_{\alpha,\sigma}^\dagger \), which depend on the interactions \( U_n \), allow us to rewrite the operator \( \hat{H}_G \) as \( \hat{H}_G = \hat{H}_{\text{kin}} + K_G \), with a kinetic energy operator \( \hat{H}_{\text{kin}} = -\sum_{\alpha, \sigma} \sum_{n=1}^{m-1} \hat{G}_{\alpha,\sigma}^\dagger \hat{G}_{\alpha,\sigma} \) and a constant \( K_G = 2N_c \sum_{n=1}^{m-1} z_a \). The kinetic part, \( \hat{H}_{\text{kin}} \), is quadratic in the original fermionic operators \( \hat{c}_{i+n,\sigma} \) and can hence be diagonalized, leading to an effective, interaction dependent band structure. In fact, the dispersion relations thereby obtained are identical to the energy bands of \( \hat{H}_0 \) in Eq. (1a), but the on-site potentials \( \epsilon_n \) are now replaced by the renormalized energies

\[
\epsilon_n^R = \epsilon_n + U_n - q_U.
\]

It is this renormalization which can lead to an effective upper flat band. In the ground state \( |\Psi_g \rangle \) of \( \hat{H} \) with \( \langle \hat{H}_G + \hat{H}_P | |\Psi_g \rangle = 0 \) (see below), this flatness is unaffected by the presence of \( \hat{H}_P \) in Eq. (2) since \( \langle \hat{H}_P | |\Psi_g \rangle = 0 \).

Thus we find the very remarkable result that a dispersive band structure of noninteracting electrons can be tuned by an interaction to yield an effective upper flat band of the interacting, many-electron system; an example is given in Fig. 3 for a selected parameter set. The effectively flat band is half-filled for the total number of particles \( N = 2N_\Lambda - N_c = N_c^* \), and is more than half-filled for \( N > N_c^* \). Such an interaction induced upper flat band is possible only if the local interactions \( U_n \) differ on at least one site in the unit cell. We note that properties of the exact ground state can only be deduced for the states in the upper band, the physics of the lower bands is not accessible by the here applied method [as indicated by the question mark in Fig. 3(b)].
The operator $\hat{Q}_N^\dagger = \prod_{y=1}^N \hat{c}_{n,k,-\sigma}^\dagger$ is a product of $N$ arbitrary, but different, $\hat{c}_{n,k,-\sigma}$ operators. That Eq. (6) is indeed a ground state follows from the fact that $\hat{G}_{\alpha,k,\sigma}$ anticommutes with the fermionic creation operators $\hat{c}_{n,k,-\sigma}$ and hence also with the operators in $\hat{Q}_N^\dagger$. Because of the free electrons with spin $-\sigma$ introduced by $\hat{Q}_N^\dagger$ the ground state Eq. (6) contains also electrons in plane-wave like states. Furthermore, since $E_g = C_g$, one finds a vanishing charge excitation gap $\delta \mu = E_g(N+1) - 2E_g(N) + E_g(N-1) = 0$ for $N > 1$.

In order to verify the extended character of the groundstate Eq. (6) we calculate again the expectation value of the hopping term $\Gamma_1(r) = \langle \Psi_g(N^* + \hat{N}) | \hat{c}_{1+r_x+\sigma}^\dagger \hat{c}_{1+r_x+\sigma}^\dagger + H.c. | \Psi_g(N^* + \hat{N}) \rangle$ specifically for $\hat{N} = 1$ and $\hat{Q}_1 = \hat{c}_{2,k^{(i)}(-\sigma)}^\dagger$, where $k^{(i)}$ is the arbitrary momentum of the electron added above $N = N^*$. In the thermodynamic limit of the pentagon-chain the result is

$$\Gamma_1(r) = \Gamma_0(r)[1 - A(k^{(i)})/B(k^{(i)})].$$

Here $\Gamma_0(r)$ is the plane-wave result for a free electron in a Bloch state, $A(k) = A_1 + A_2 \cos k \cdot \mathbf{a}$, and $B(k) = B_1 + B_2 \cos k \cdot \mathbf{a}$ holds for all $k$ with constants $A_1, A_2$ and $B_1, B_2$ (for details see Ref. [18]). This shows that the localization length is indeed infinite.

For pentagon chains without external links (i.e., when the sites $i + \mathbf{r}_0$ and $i + \mathbf{r}_1$ in Fig. 2 are missing) the same solutions are found, but the regions of parameter space where they exist are shifted.

We emphasize that in the case of Mielke-Tasaki ferromagnetism, i.e., flat-band ferromagnetism in a half-filled lowest flat band [12], both the flat band and the connectivity conditions (the overlap of the local Wannier functions) necessary for the emergence of this type of ferromagnetism, result from the bare band structure determined by $\hat{H}_0$. By contrast, we have shown here that the interaction may
be employed to tune a fully dispersive bare band structure to become partially flat. The results apply to the high-density region where Brocks et al. conjectured the presence of strong correlations in acene and thiophene organic molecular crystals and the stabilization of magnetic phases [14]. Using the $\hat{H}_0$ parameters from Fig. 3, the matching conditions provide for the upper (bare) band a width of $W / \ell = 0.15$, with $0.2 \leq U_n / W \leq 2.3$. For other parameters in $\hat{H}_0$ the parameter space domain $D$ [18] allows for even higher values of $U_n / W$.

Regarding the experimental realization of the ferromagnetic and the half-metallic states derived above, we note that the required electron doping of the pentagon chains can, in principle, be achieved [20] by two means: first by raising the Fermi level by selecting appropriate side groups, and second by field-effect doping in a double-layer transistor structure [21]. Specifically for polythiophene with an estimated density of $10^{14}$ pentagon rings/cm$^2$ [22], electron densities of the order $10^{15}$ carriers/cm$^2$ are required. As already verified these electron densities are experimentally achievable [23].

In summary, by employing a rigorous analytic method we have constructed exact ground states for a multiorbital pentagon Hubbard chain. The ferromagnetism and the half-metallicity of the derived solutions originate from an unexpected mechanism in multiorbital polygon chains with different site-dependent Coulomb interaction strengths. For high electron densities with the top band at least half-filled the interactions are capable of turning this dispersive band into an effectively flat band in an extended parameter region. The obtained solutions therefore point to a new route for the design of ferromagnetic pentagon-chain polymers.

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[17] A similar strategy with qualitatively similar results can be presented in Fig. 3(a), and (iii) the expectation value of the hopping term, Eq. (7).
[18] We note that Eq. (4) describes only the case of maximal spin projection $S_{\text{max}}$. The ground states in the other spin sectors $S_z = N_{\uparrow} / 2 - \tilde{n}$, $\tilde{n} < S_{\text{max}}^\uparrow = \{ S_{\uparrow}^\uparrow | \Psi_{\uparrow}(N^\uparrow, \tilde{n}) \} = (S_{\uparrow}^\uparrow)^{\text{at}}| \Psi_{\uparrow}(N^\uparrow) \}$, where $\tilde{s}_{i} = \sum_{n=1}^{S_{\uparrow}^\uparrow} \sum_{r} \delta_{\uparrow}(i + r), \tilde{s}_{i} = \delta^\uparrow_{i + r}$, $\tilde{n} = 1, \ldots, N_{\uparrow}$. Since $\tilde{P}_{\uparrow} \tilde{s}_{i} \tilde{s}_{i} \tilde{P}_{\uparrow} = \tilde{s}_{i} \tilde{P}_{\uparrow} \tilde{s}_{i} \tilde{P}_{\uparrow}$, $\tilde{G}_{\uparrow}(N^\uparrow, \tilde{n})$ remains in the ground-state manifold.